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Broad Stopband, Low-Loss, and Ultra-Compact Dual-Mode Bandpass Filter Based on HMSIRC

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Abstract: In this investigation, an ultra-compact dual-mode bandpass filter (BPF) with a wide stopband response is realized by using a half-mode substrate-integrated rectangular cavity (HMSIRC). The HMSIRC resonator is designed with a cavity that is rectangular in shape and has metallic vias along three of the sides. The fourth side is open-ended and contains microstrip feed lines. For the purpose of constructing a magnetic wall, a rectangular slot is cut into each of the HMSIRC's three edges. In order to produce an electrical wall that may generate a variety of resonances, the side with the open edges is provided with a single metallic via in the center. After that, a second-order BPF is generated by loading a transverse slot in the middle of the BPF, which enables independent frequency regulation of the mode frequencies. The eigen-mode analysis; field distributions; coupling matrix; and full-wave simulation of the proposed HMSIRC filter topology are used to develop the working principle of the filter. A second-order BPF is realized, constructed, and experimentally validated in order to provide evidence that the theory is correct. The BPF prototype achieves satisfactory performance thanks to its compact footprint of $0.028 \lambda_g^2$; its broad passband of 15.9%; its low insertion loss of 0.41 dB; and its wide stopband of $4.36 f_0$ with a rejection level greater than 20 dB. Both the measured and EM-simulated responses of the BPF are very consistent with one another.

Keywords: substrate-integrated rectangular cavity; bandpass filter; dual-mode; broad stopband



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1. Introduction

The development of bandpass filters (BPFs) with low cost, compact size, better frequency selectivity, and broadband suppression has been greatly influenced by the incredible advancements in wireless communication technology. In filter design for base stations, waveguide structures are frequently used due to their low loss, high power handling capability, and high Q-factor. However, integrating a rectangular waveguide with other planar microwave components is costly and challenging. Recently, substrate-integrated waveguides (SIW) have received a lot of attention because they are inexpensive, lightweight, feature low insertion loss, are simple to fabricate, and work well with other planar circuits. These characteristics make them ideal for meeting the high-performance demands imposed on filter designs [1–3].

Several BPFs have been constructed using SIW technology [4–47]. Narrow and wide-band BPFs have been realized using the SIW coaxial cavity, as described in [4]. The authors of [5] describe a three-pole BPF employing a dual-mode circular SIW cavity with tunable transmission zeros. To implement a SIW filter with a wide stopband, [6] uses a variant of the mode suppression technique. There is an analysis and implementation of filters based on quarter-mode substrate integrated waveguides (QMSIW) in [7]. The authors of [8] describe a BPF with a wide upper stopband response that was built using a multi-layered SIW. Triple-mode BPFs based on a SIW square cavity filled with CSRRs are shown in [9]. The authors of [10] describe SIW square cavities with orthogonal and in-line ports that

are used to build BPFs with adaptable outputs. The authors of [11] describe bandpass filters that have been created using dual-mode SIW cavities operating within various boundaries. Combining QMSIW and EMSIW cavities allows for a small BPF with a wide stopband response, as shown in [12]. The authors of [13] describe a wideband filter and diplexer using a dual-mode SIW cavity with variable reactions. Using dual-mode SIW radial cavities, a wideband BPF has been realized [14]. Dual-mode miniaturized BPFs have been realized using half-mode SIW cavities [15]. The authors of [16] describe how it has been suggested that dual-mode SIW cavities be used to construct box-like BPFs with a wide stopband response. The use of perturbed SIW cavities has allowed for the development of high-order BPFs, as shown in [17]. Using a combination of microstrip technology and SIW, the authors of [18] explore the fabrication of a small BPF with a wide stopband response. Using half-mode SIW with stepped-impedance resonators, [19] creates a compact bandpass filter. A broadband SIW bandpass filter based on electromagnetic bandgap (EBG) units for wide stopband response has been constructed with good selectivity [20].

A HMSIW fan-shaped circular cavity has been examined in order to build a bandpass filter with decreased size and order-extensible capabilities [21]. Within the scope of this study, a bandpass filter of the second order was upgraded to a filter of the fourth order without the cavity's actual size having to be increased. A HMSIW cavity was used to construct planar bandpass filters with a small size for the research presented in [22]. These fourth-order filters have a fractional bandwidth of 31.8%, one/two transmission zeros, and a reduced footprint area of $0.159 \lambda_g^2$. Using a T-septum HMSIW cavity, third-order bandpass filters have been created and described in [23]. These filters have an insertion loss of less than 2.61 dB and a fractional bandwidth of 17.77%, while also having a wide stopband of $10.37 f_0$. Higher-order SIW resonators were used in the construction of a narrow-band filter that was published in [24]. This filter offers high selectivity, a wide stopband, and three transmission zeros. Utilizing a SIW cavity equipped with perturbing vias and a complementary split-ring resonator, an application-specific bandpass filter for frequencies below 6 GHz was developed and described in [25]. In addition to having a fractional bandwidth of 1.16% and high selectivity, this filter has an insertion loss of 2.9 dB. The article [27] describes the construction of a bandpass filter for X-band applications that is based on a dual-mode SIW cavity. This filter has two transmission zeros located at 10.75 GHz and 13.3 GHz, and it operates at a frequency of 12 GHz. The fractional bandwidth of this filter is 11%. Utilizing a double-layer HMSIW resonator resulted in the development of a bandpass filter that was described in reference [28]. This filter makes use of a microstrip defect structure in order to provide a wide stopband response. Using a rectangular SIW cavity filled with a D-shaped ring resonator, the research paper [29] describes the construction of a bandpass filter with two bands. Applications that need frequencies lower than 6 GHz may make use of this filter since it works at 2.66 and 3.54 GHz. The authors of [30] describe a SIW filter with asymmetric responses. This filter also makes use of a non-resonating node and positive coupling in order to improve its selectivity. A bandpass filter that is based on SIW cavities has been constructed and described in [31]. This filter achieves harmonic suppression by combining the functionality of the SIW cavity with that of interdigital resonators. The authors of [32] describe a broadband bandpass filter on HMSIW cavities with a size reduction that has been created. Transmission zeros and favorable stopband responses are generated using a three-stage stepped impedance resonator in this filter. An in-line HMSIW cavity is used to create a narrow-band bandpass filter, as demonstrated in [33]. This filter enhances selectivity by generating limited transmission zeros using interdigital slots to create quasi-elliptic responses. The authors of [34] describe a bandpass filter operating at 6 GHz for 5G applications that has been realized using a rectangular SIW cavity. This filter employs D-shaped resonators for size reduction and wide stopband responses. The authors of [35] describe the creation of a bandpass filter that is based on a rectangular SIW cavity that is loaded with many complimentary split-ring resonators. This filter has an insertion loss

of 1.5 dB, a stopband response that ranges from 6.4 GHz to 7.8 GHz, and a fractional bandwidth that is 30% wider than the full bandwidth.

A broadband bandpass filter has been realized using SIW in conjunction with defective ground structures [36]. This 8.98 GHz operating filter has a fractional bandwidth of 47.4%, an insertion loss of 1.5 dB, and a strong roll-off factor. The authors of [37] describe a SIW cavity loaded with composite right/left-handed transmission lines and complementary split-ring resonators that is used to create a dual-frequency bandpass filter. The filter has a 3% and a 4.2% bandwidth at its 5 GHz and 7.5 GHz resonant frequencies, respectively. The authors of [38] describe a flexible bandpass filter based on a SIW hexagonal resonator. This filter has an insertion loss of 2.01 dB and a fractional bandwidth of 2.92 percent. The authors of [39] describe a SIW bandpass filter consisting of two resonators and three inverters. A bandpass filter has been constructed utilizing a SIW cavity with iris resonators, as described in [40]. The frequency of operation for this filter is 9.77 GHz, and it has a fractional bandwidth of 12.17% and an insertion loss of 1.19 dB. The paper [41] describes the construction of a bandpass filter using a SIW cavity with a defective ground structure in order to get wideband responses. With a passband ranging from 3.0 GHz to 11.0 GHz, an insertion loss of 1.2 dB, and a notched band, this filter is able to achieve a smaller footprint. The authors of [42] describe a narrow bandpass filter that has been realized by using a rectangular SIW cavity loaded with inductive posts on the top surface. The center frequency of this filter is 12.2 GHz, and it has an insertion loss of 1.22 dB and a fractional bandwidth of 1.475%. The authors of [43] describe a dual-mode bandpass filter that has been constructed by using a SIW cavity loaded with cross-shaped slots. This filter has a fractional bandwidth of 9.1% at the center frequency of 7.5 GHz and two transmission zeros at 12.5 GHz and 15 GHz, respectively. Using a rectangular SIW cavity in conjunction with stepped impedance resonators, the authors of [44] were able to create a bandpass filter with a reduced size. This filter has a footprint size of $0.3 \lambda_g^2$, it works at 4.8 GHz, it offers four transmission zeros, and it has a fractional bandwidth of 13%. The authors of [45] describe a dual-mode bandpass filter operating at 5.8 GHz, which has been constructed by utilizing a SIW cavity loaded with a circular patch slot. The authors of [46] describe a bandpass filter with high design flexibility that has been realized by using a SIW cavity in non-resonating mode. The authors of [47] describe a rectangular SIW cavity loaded with two pairs of complementary rectangular split-ring resonators. This filter has a transmission zero at 5.9 GHz, an insertion loss of 2.4 dB, and a bandwidth of 320 MHz at 3 dB.

An ultra-compact dual-mode bandpass filter (BPF) with a broad stopband response is constructed in this study by using a half-mode substrate-integrated rectangular cavity (HMSIRC). Eigen-mode analysis, field distributions, the coupling matrix, and full-wave simulation of the proposed HMSIRC filter topology are used to construct the filter's working theory. Realization, prototyping, and experimental validation of a second-order BPF are accomplished to prove the concept. The filter exhibits the following key features:

- (i) It occupies a footprint area of only $0.028 \lambda_g^2$, which is extremely small compared to the dual-mode BPFs that have previously been reported;
- (ii) Its insertion loss is 0.41 dB;
- (iii) It exhibits a passband of 15.9%, a broad stopband response of $4.36 f_0$, and a rejection level of 20 dB.

2. Design and Analysis of the HMSIRC-Based Bandpass Filter

2.1. Configuration and Working Principles

The proposed dual-mode bandpass filter layout and coupling topology are shown in Figure 1. The filter is constructed using a transverse slot, an open-ended slot, a metallic via, and a half-mode substrate-integrated rectangular cavity (HMSIRC). Initially, an HMSIRC is

$$f_{mn0}^{HMSIRC} = \frac{1}{2\sqrt{\epsilon_r}} \sqrt{\left(\frac{m}{L_{eq}^{HMSIRC}}\right)^2 + \left(\frac{n}{2W_{eq}^{HMSIRC}}\right)^2} \quad (1)$$

$$f_{mn0}^{HMSIRC} = \frac{1}{2\sqrt{\epsilon_r}} \sqrt{\left(\frac{m}{L_{eq}^{HMSIRC}}\right)^2 + \left(\frac{n}{2W_{eq}^{HMSIRC}}\right)^2} \quad (1)$$

where $\begin{cases} L_{eq}^{HMSIRC} = L_S - 1.08 \frac{S_0^2}{S_1} + 0.1 \frac{S_0^2}{L_S} \\ W_{eq}^{HMSIRC} = W_S - 1.08 \frac{S_0^2}{S_1} + 0.1 \frac{S_0^2}{W_S} \end{cases}$ is the diameter S_0 of the vias, and their longitudinal distance S_1 is chosen by applying the following criteria: $S_0/\lambda \leq 0.1$ and $S_0/S_1 \geq 0.5$. This is to keep the radiation losses reasonably low [2]. Next, a magnetic wall is created by etching an open-ended slot in the cavity with metallic vias on each of its three sides.

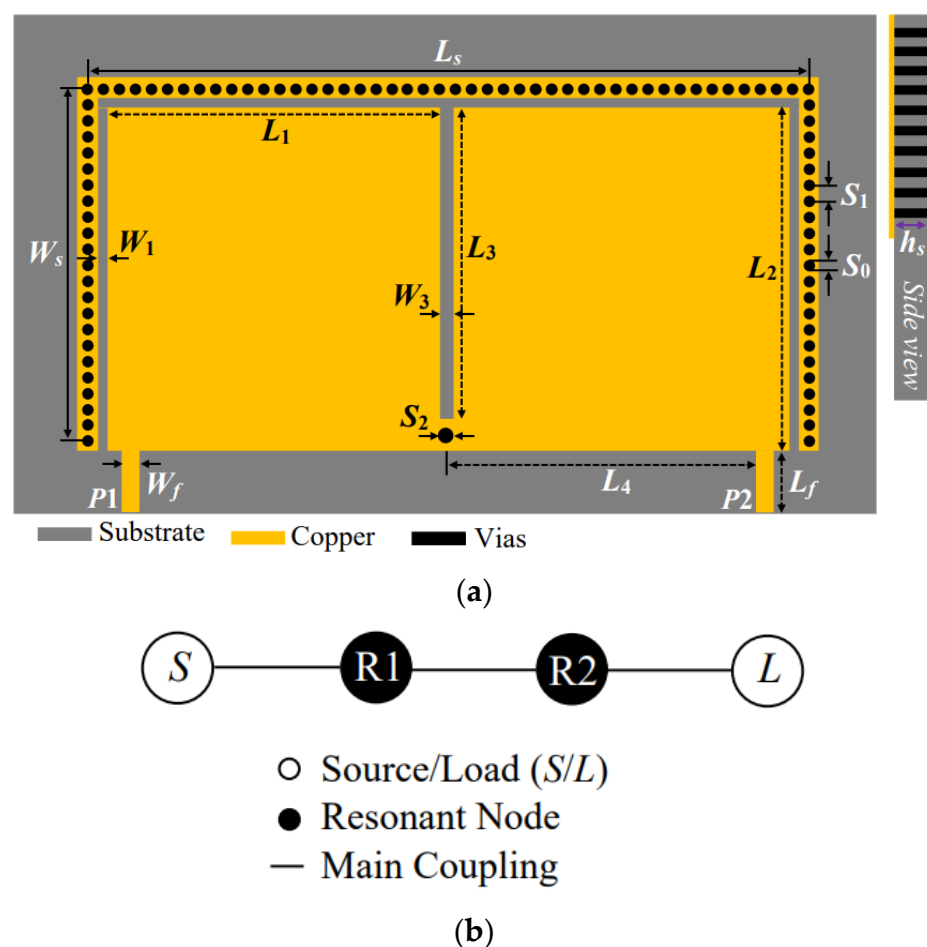


Figure 1. (a) Half-mode SIRC-based bandpass filter configuration. The design parameter values are: $L_s = 53.1$, $W_s = 26.1$, $L_1 = 7.0$, $L_2 = 24$, $L_3 = 23.5$, $L_4 = 25.3$, $L_f = 5.0$, $W_1 = 0.6$, $W_3 = 0.65$, $W_f = 1.18$, $S_0 = 0.6$, $S_1 = 0.9$, $S_2 = 0.5$, and $h_s = 0.508$; unit: mm. **(b)** The filter's coupling topology.

Subsequently, a metallic via is placed in the middle of the cavity, which generates an electric wall. These arrangements provide multiple modes of resonance. Finally, a transverse slot is introduced at the middle of the cavity to control the mode frequencies, which enables us to develop a dual-mode bandpass filter. The top of the HMSIW is then etched with a rectangular ring slot, which increases the capacitive loading of the cavity. This, in turn, provides an operating frequency that is lower than the cutoff frequency of the cavity. Because of this result, it is possible to accomplish size reduction. The substrate used to create the filter is Roger's RO4003C, which has a thickness of 0.508 mm, a permittivity of 3.38, and a loss tangent of 0.0021.

2.2. Synthesis of a Dual-Mode Bandpass Filter

The suggested dual-mode BPF using the half-mode SIRC cavity is shown in Figure 1a. The rectangular slot along the three sides of the half-mode cavity produces a magnetic wall, whereas a centrally loaded metallic via creates an electric wall. This arrangement generates various modes. Figure 2 exhibits the distributions of the electric field to express the various modes. Without loading the slots, the resonant frequencies of the HMSIW cavity modes TE_{110} , TE_{210} , TE_{310} , and TE_{120} are 3.45 GHz, 4.35 GHz, 5.52 GHz, and 6.35 GHz, respectively. Because of the slot loading, the resonant frequencies of these modes are decreased due to the increase in capacitive loading on the top surface of the cavity, which results in the realization of a second-order filter at a lower frequency. Figure 3 depicts the distributions of the vector H-field to examine the influence of the transverse slot. Since the transverse slot is perpendicular to the vector H-field directions of the TE_{110} and TE_{120} modes, as shown in Figure 3a,d, it has a profound effect on these modes. From Figure 3b,c, it is observed that the H-field direction of the modes TE_{210} and TE_{310} is parallel to the transverse slot, which has no significant effect on the resonant frequencies. The effect of the length L_3 of the transverse slot on the resonant frequencies of the modes is shown in Figure 4. As it can be seen, the resonant frequencies of the TE_{110} and TE_{120} modes are decreased by increasing the length of the transverse slot, whereas there is no significant change in the resonant frequencies of the TE_{210} and TE_{310} modes. It is inferred that the length of the transverse slot can control the resonant frequency of the modes that allow us to realize a second-order BPF.

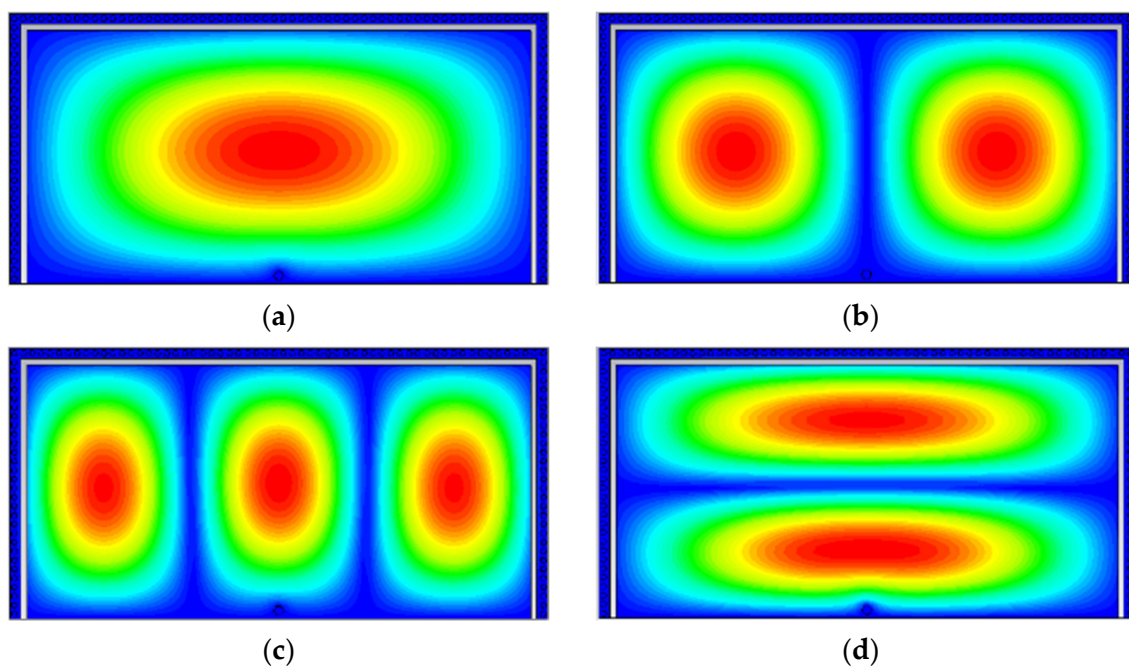


Figure 2. Electric field distribution of four different modes: (a) TE_{110} mode, (b) TE_{210} mode, (c) TE_{310} mode, and (d) TE_{120} mode.

The coupling coefficient $K_{j,j+1}$, the source quality factors Q_S , and the load quality factor Q_L can be determined as [26]:

$$Q_S = Q_L = \frac{f_0}{\Delta f_{\pm 3\text{dB}}} \quad (2)$$

$$K_{j,j+1} = \frac{f_{m2}^2 - f_{m1}^2}{f_{m2}^2 + f_{m1}^2} \quad (3)$$

where the center frequency and the 3 dB bandwidth are denoted by f_0 and $f_{\pm 3\text{dB}}$; f_{m1} and f_{m2} stand for mode frequencies. The transverse slot's length allows us to predict the bandwidth of the filter. The unloaded quality factor Q_u is computed to be 382 using eigen-mode analysis and factoring in losses attributable to radiation, conductor, and dielectric.

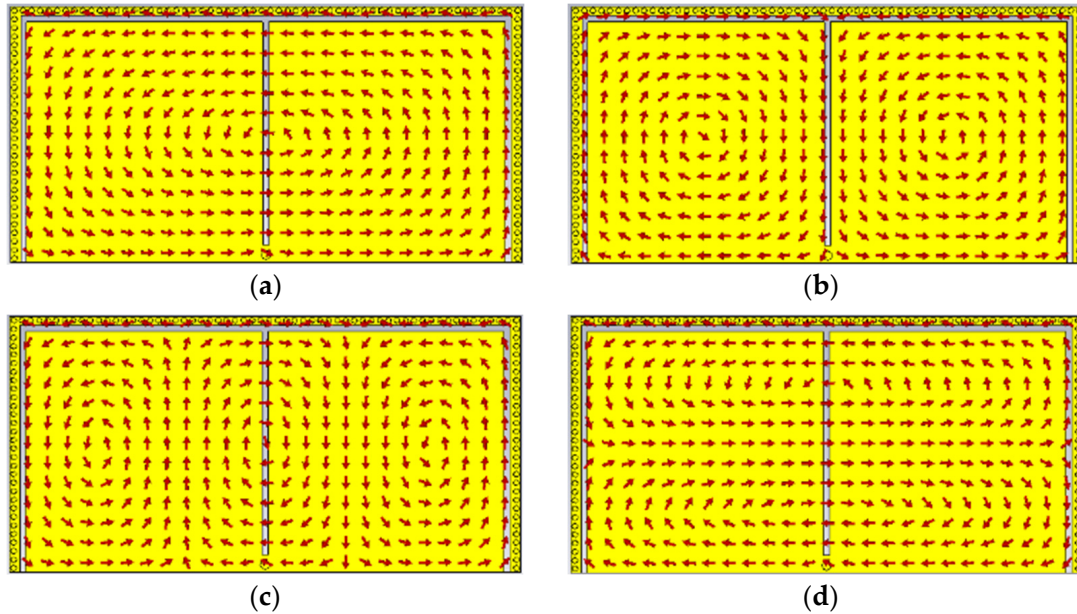


Figure 3. Vector H-field distribution of four different modes: (a) TE_{110} mode, (b) TE_{210} mode, (c) TE_{310} mode, and (d) TE_{120} mode.

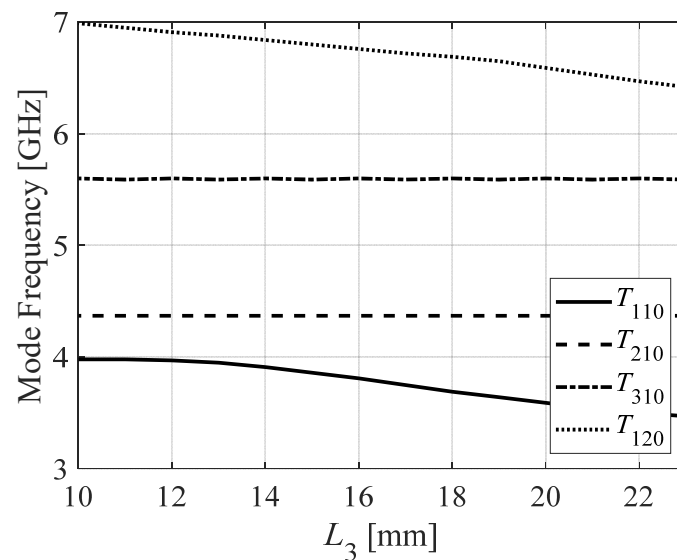


Figure 4. Variation of resonant frequencies for different modes.

For verification, a second-order BPF has been synthesized. The circuit exhibits a center frequency of 0.835 GHz, a return loss of 26.3 dB, and a relative bandwidth of 5.43%. The synthesis method of [3] has been used to compute the coupling coefficient, external quality factor, and coupling matrix as $K_{12} = 0.0528$, $Q_S = Q_L = 6.5$, and

$$M = \begin{bmatrix} 0 & 1.4754 & 0 & 0 \\ 1.4754 & 0 & 2.2887 & 0 \\ 0 & 2.2887 & 0 & 1.4754 \\ 0 & 0 & 1.4754 & 0 \end{bmatrix} \quad (4)$$

The BPF's coupling coefficient and quality factor are controlled via a transverse slot. Figure 5 shows how the coupling coefficient of the BPF varies with the slot width. The coupling coefficient K_{12} is shown to decrease with increasing slot width W_3 . S-parameters calculated by the coupling matrix and electromagnetic simulation for the proposed BPF are shown in Figure 6. The total loss of the proposed BPF is attributed to radiation loss, dielectric loss, and conductor loss. Figure 7 shows the estimated losses of the second-order BPF. As illustrated, the total loss, dielectric plus radiation loss, and radiation loss are all less than 0.143, 0.095, and 0.075, respectively. As a result, the proposed BPF exhibits a very low insertion loss of 0.41 dB.

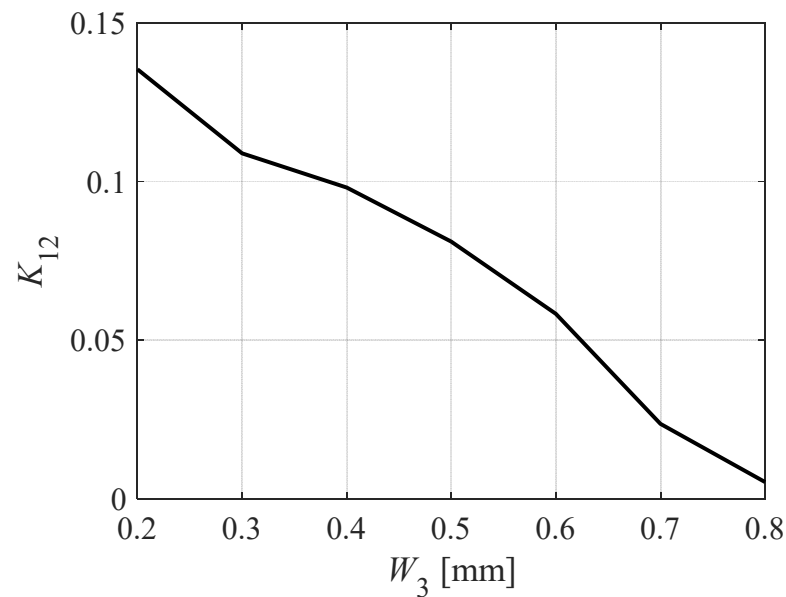


Figure 5. Variation of coupling coefficient as a function of W_3 .

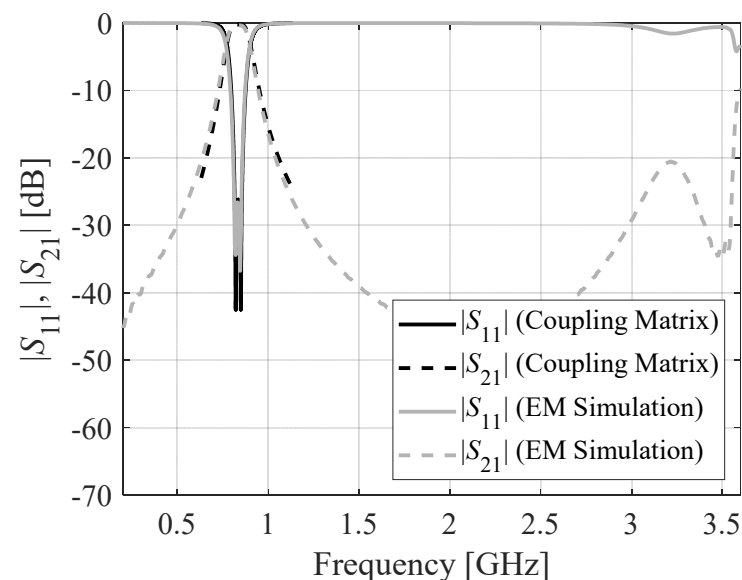


Figure 6. Dual-mode BPF S-parameters estimated using coupling matrix and EM simulation.

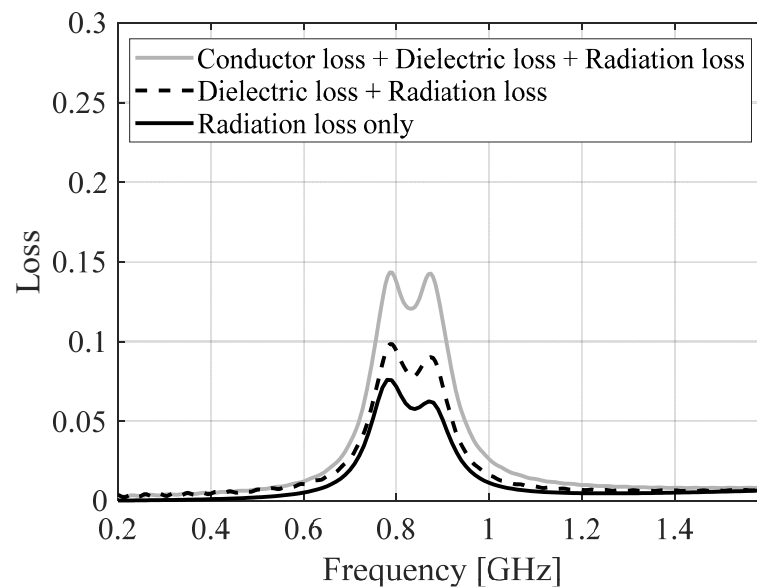


Figure 7. Estimated losses of the proposed second-order BPF.

2.3. Analysis of Insertion Loss

In this subsection, insertion loss owing to frequency enhancement is investigated. By lowering the value of the cavity parameter L_s , the suggested HMSIW-based bandpass filter achieves a higher resonant frequency. In order to observe the effect on insertion loss with an increase in frequency, we varied the parameter L_s and obtained the EM simulations. Figure 8 shows the insertion losses at different frequencies with varying L_s . It is found that there are no significant changes in the insertion loss when frequency increases. The insertion loss at each center frequency is determined as shown in Table 1. As the resonant frequency rises from 0.839 GHz to 0.938 GHz, the insertion loss rises from 0.362 dB to 0.37 dB, which is only a 2.2% increase.

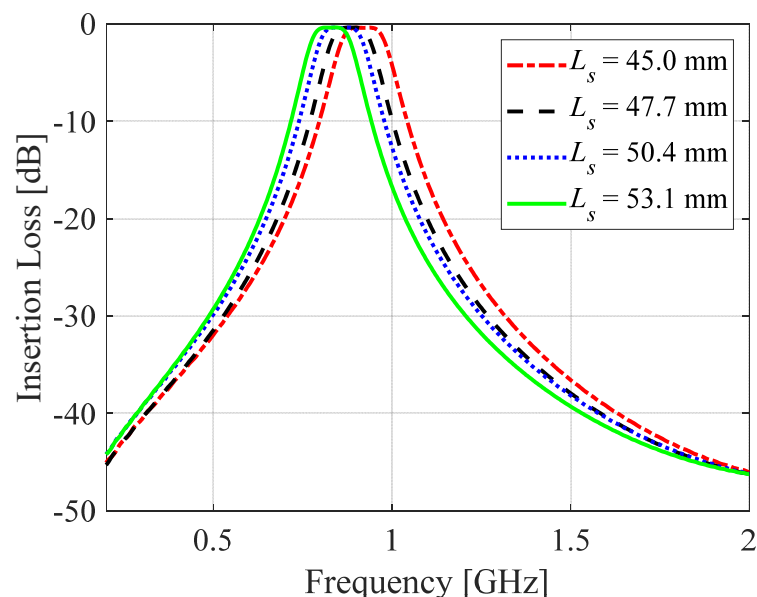


Figure 8. Various insertion losses with an increase in operating frequency for various values of L_s .

Table 1. Insertion loss with an increase in operating frequency.

L_s (mm)	f_0 (GHz)	IL (dB)
53.1	0.839	0.362
50.4	0.86	0.367
47.7	0.891	0.364
45	0.938	0.37

2.4. Analogous Circuit Model of a Second-Order Bandpass Filter

The order of the filter can be determined either by the number of poles or the number of zeros; whichever number is higher will determine the order. The bandpass filter based on HMSIW that was presented is a second-order filter due to the fact that it creates two poles. In order to verify the filter, an analogous circuit model is created for the suggested second-order HMSIW-based bandpass filter, as shown in Figure 9. The metallic vias of the HMSIW may be represented as a two-wire transmission line and characterized as a shunt inductor by L_{mv} . The magnetic and electrical couplings at the microstrip feed lines can be described using the electrical parameters L_{01} and C_{01} , respectively. The HMSIW rectangular and transverse slots are portrayed as shunt connected L_{or} and C_{or} . The mutual coupling that exists between cavity-backed resonators and HMSIW is shown as a series-connected L_{02} and C_{02} in the circuit model. This is a simpler form of the analogous circuit model, which is verified using the Keysight ADS simulator. Figure 10 illustrates the circuit as well as the EM-simulated S-parameters of the proposed HMSIW-based second-order bandpass filter. Both the circuit and the EM data show that there is a high level of consistency in the passband regarding the reflection coefficient and the insertion loss.

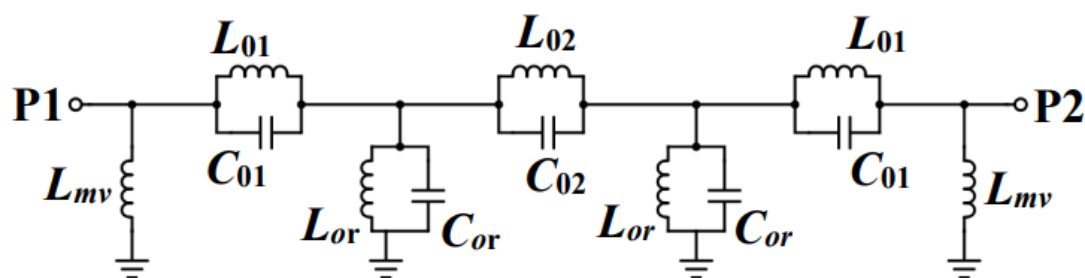


Figure 9. Analogous circuit model of the proposed HMSIW-based BPF. The electrical parameters are $L_{mv} = 15.0061$ nH, $L_{01} = 4.3357$ nH, $C_{01} = 0.02$ pF, $L_{02} = 16.8144$ nH, $C_{02} = 0.02$ pF, $L_{or} = 2.5092$ nH, and $C_{or} = 19.2436$ pF.

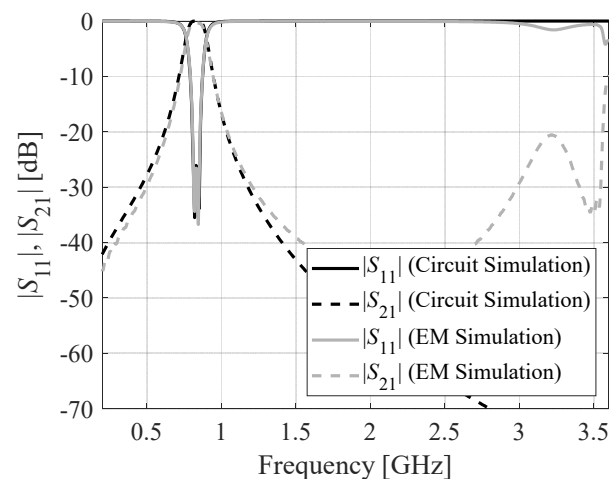


Figure 10. Circuit and EM simulation S-parameters of the proposed second-order BPF.

3. Fabrication, Measurement, and Results

For verification of the concept, a second-order bandpass filter based on the HMSIRC has been synthesized, manufactured, and experimentally validated. The suggested filter works at 835 MHz. The suggested SIW-based second-order BPF operates at 835 MHz and is designed for lower-band (600 MHz to 6 GHz) 5G applications. Eventually, lower frequency bands of 5G will be used for industrial automation and the Internet of Things in addition to its more traditional corporate applications. As a result, in order to fulfill the requirements of 5G applications, we developed the SIW-based BPF with a lower operating frequency. The circuit prototype has been shown in Figure 11. Figure 11b shows the measurement setup for the fabricated filter. We employ a Rohde and Schwarz vector network analyzer to measure this SIW-based BPF. The BPF prototype is ultra-compact, with a size smaller than $0.028 \lambda_g^2$, where λ_g is the guided wavelength at the resonant frequency. A two port Rohde and Schwarz vector network analyzer has been used to conduct the measurements, which were then compared to the EM-simulated responses shown in Figure 12. At the resonant frequency, the observed insertion loss $|S_{21}|$ is 0.41 dB, while the insertion loss $|S_{21}|$ from the electromagnetic simulation is 0.36 dB. The BPF exhibits a 3 dB fractional bandwidth of 15.8%. Additionally, it features a broad stopband response of $4.26 f_0$.

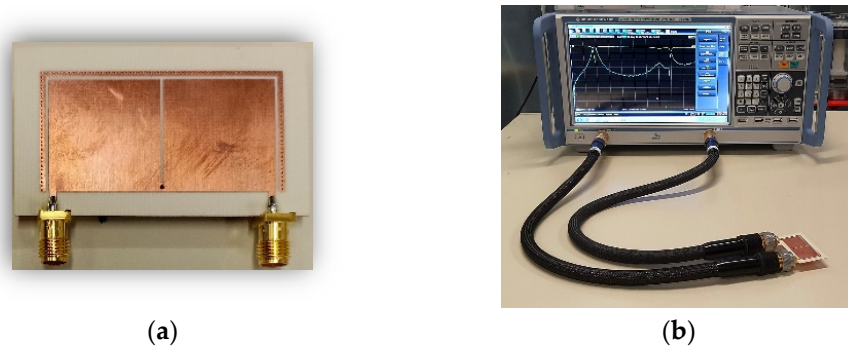


Figure 11. Experimental validation of the proposed filter: (a) BPF prototype and (b) measurement setup.

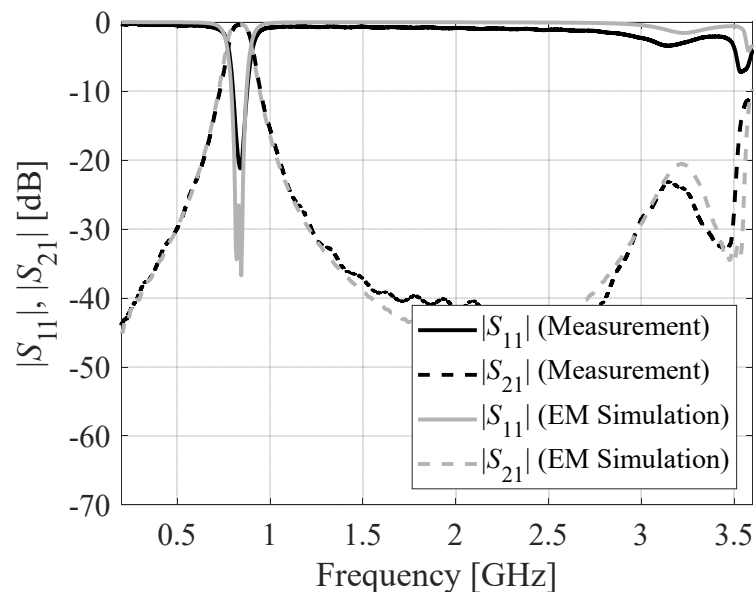


Figure 12. EM-simulated and measured S-parameters of the proposed BPF.

A comparison of the proposed BPF with state-of-the-art BPFs reported in the literature can be found in Table 2. The proposed second-order BPF has a smaller footprint than the filters described in [4–22], with the exception of the filter described in [23]. The insertion

loss of the proposed filter is also significantly lower, at 0.41 dB, than the filters described in [4–23]. The suggested BPF has a larger fractional bandwidth despite its small size compared to the filters given in [4–21], except for the filters presented in [22,23]. It is inferred that the proposed BPF prototype achieved a low insertion loss, a broad stopband response, and a remarkably small size as compared to the benchmark.

Table 2. A comparison of the proposed BPF with the state-of-the-art BPFs.

Ref	f_c (GHz)	FBW (%)	IL (dB)	N	Upper Stopband	Size (λ_g^2)	SF (%)
[4]	8	20	0.7	2	14 dB@1.81 f_0	0.176	32.9 ^{\$}
[5]	8	3.51	2.15	3	20 dB@1.25 f_0	0.804	28.53
[6]	7.55	1.84	3.22	3	20 dB@3.85 f_0	1.61	22.2
[7]	4	16	1.02	3	15 dB@1.75 f_0	0.0625	40.9
[8]	5	6.6	0.9	3	30 dB@4.2 f_0	NR	30.2
[9]	10.8	16.5	1.5	3	20 dB@1.29 f_0	1.09	62.2
[12]	8	11	0.9	3	23 dB@0.865 f_0	0.147	25.3
[14]	5.22	-	1.62	4	20 dB@1.2 f_0	-	51.47
[15]	10	5.3	2.4	4	30 dB@1.05 f_0	1.75	36.6
[16]	10.01	3.98	1.52	4	20 dB@1.67 f_0	1.978	38.3
[17]	10	3.3	1.55	4	30 dB@1.03 f_0	2	49.27
[18]	10.11	11.7	1.22	4	20 dB@2.9 f_0	0.5	41.9
[19]	3.25	4.62	2.5	2	NA	0.051	19.85
[21]	1	12	0.83	2	20 dB@4.6 f_0	0.038	30.6 ^{\$}
[22]	4.51	26	0.57	4	20 dB@2.40 f_0	0.159	43.7
[23]	10.6	17.77	2.61	3	20 dB@10.37 f_0	0.016	26.45 ^{\$}
This work	0.835	15.8	0.41	2	20 dB@4.26 f_0	0.028	32.51 ^{\$}

FBW: three dB fractional bandwidth; IL: insertion loss; N: order; f_c : center frequency; SF: selectivity factor; and ^{\$}: based on 20 dB bandwidth.

4. Conclusions

In this paper, an ultra-compact second-order bandpass filter (BPF) based on a half-mode substrate-integrated rectangular cavity (HMSIRC) is presented. The filter was configured by using an HMSIRC, a rectangular slot, a transverse slot, and metallic vias. A full-mode SIRC was divided in half to create an HMSIRC with metallic vias on three of its sides and open-edged on the fourth side. To create the magnetic wall, a rectangular slot was created across the three via-containing sides, and to create the electric wall, a metallic via was loaded into the cavity's center. As a consequence, many resonant modes were produced. By introducing a transverse slot into the cavity, we were able to manipulate the resonant frequencies of these modes and therefore realize a second-order bandpass filter. The working principle, field distribution, coupling matrix, and loss calculation were discussed. Finally, a second-order BPF was manufactured and verified experimentally. The fabricated prototype achieves a low insertion loss of 0.41 dB, a passband bandwidth of 15.8%, and a broad stopband response of 4.26 f_0 .

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